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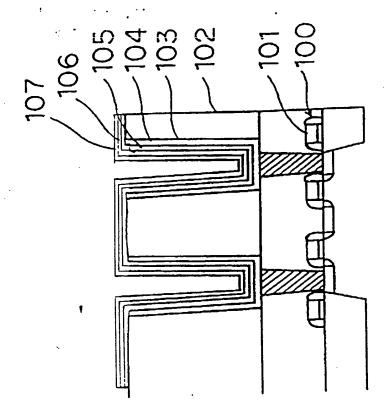
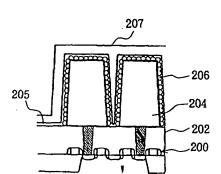


Fig. 1 Related Art



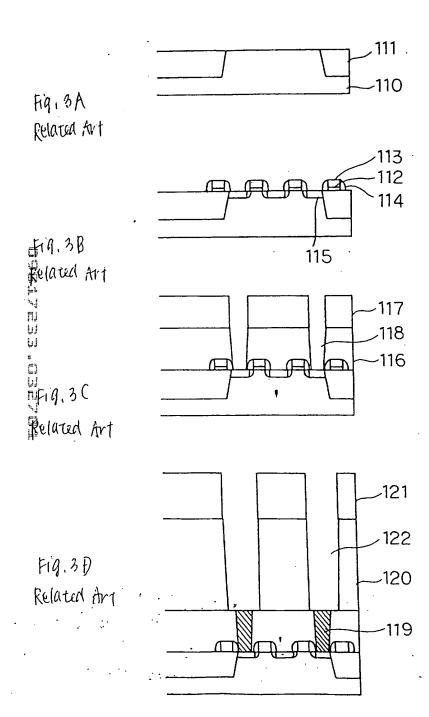
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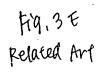


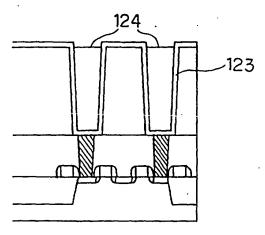
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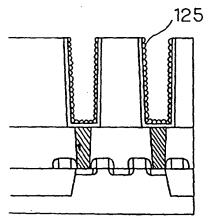
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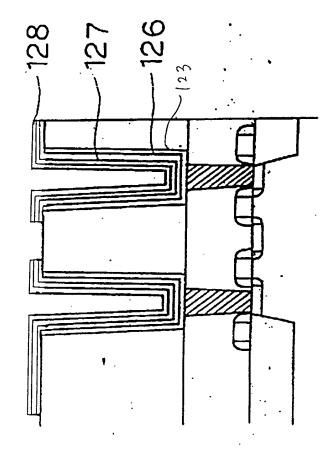
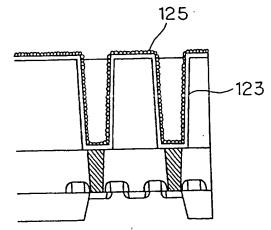


fig.39 Related Art

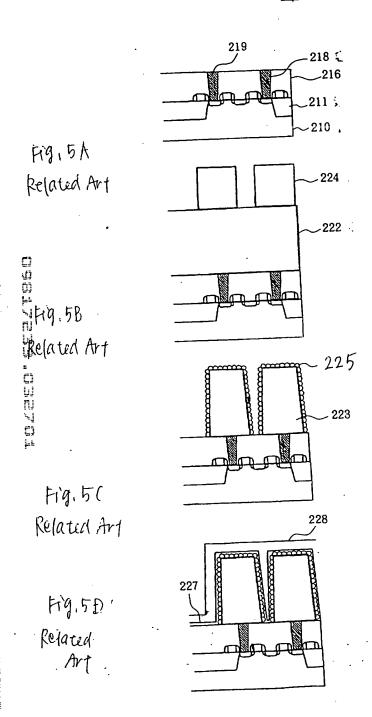
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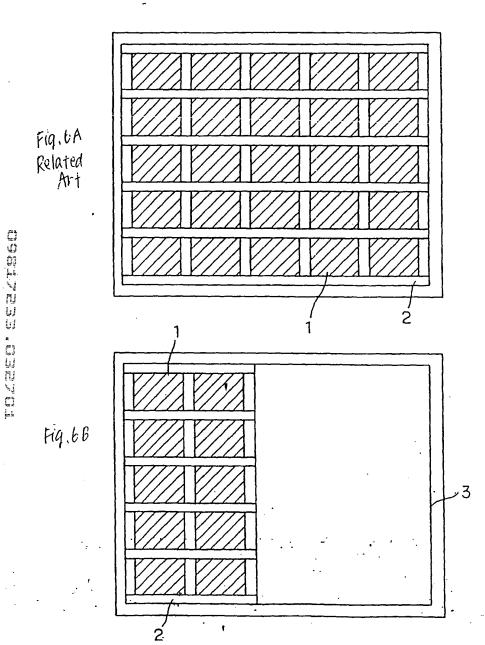




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